# UP04311

## Silicon NPN epitaxial planar transistor (Tr1) Silicon PNP epitaxial planar transistor (Tr2)

#### For switching For digital circuits

#### Features

- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

#### Basic Part Number of Element

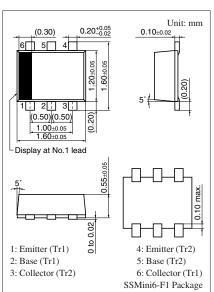
• UNR2211 (UN2211) + UNR2111 (UN2111)

#### Parameter Symbol Unit Rating Tr1 Collector to base voltage 50 V V<sub>CBO</sub> V Collector to emitter voltage V<sub>CEO</sub> 50 Collector current $I_C$ 100 mА Tr2 -50 V Collector to base voltage $V_{CBO}$ Collector to emitter voltage -50 V V<sub>CEO</sub> -100Collector current $I_{C}$ mA 125 Overall Total power dissipation $P_T$ mW 125 °C Junction temperature Ti -55 to +125 °C Storage temperature Tstg

### Absolute Maximum Ratings $T_a = 25^{\circ}C$

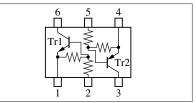
#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

#### • Tr1



#### Marking Symbol: 7X

#### Internal Connection



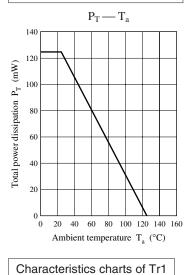
| Parameter                               | Symbol                         | Conditions   | Min  | Тур | Max  | Unit |
|---|--------------------------------|--|------|-----|------|------|
| Collector to base voltage               | V <sub>CBO</sub>               | $I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$  | 50   |     |      | V    |
| Collector to emitter voltage            | V <sub>CEO</sub>               | $I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$  | 50   |     |      | V    |
| Collector cutoff current                | I <sub>CBO</sub>               | $V_{CB} = 50 \text{ V}, I_E = 0$   |      |     | 0.1  | μΑ   |
|   | I <sub>CEO</sub>               | $V_{CE} = 50 \text{ V}, I_B = 0$   |      |     | 0.5  |      |
| Emitter cutoff current                  | I <sub>EBO</sub>               | $V_{EB} = 6 V, I_C = 0$  |      |     | 0.5  | mA   |
| Forward current transfer ratio          | h <sub>FE</sub>                | $V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$                                    | 35   |     |      |      |
| Collector to emitter saturation voltage | V <sub>CE(sat)</sub>           | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$                                  |      |     | 0.25 | V    |
| High-level output voltage               | V <sub>OH</sub>                | $V_{CC} = 5 \text{ V}, \text{ V}_{B} = 0.5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$ | 4.9  |     |      | V    |
| Low-level output voltage                | V <sub>OL</sub>                | $V_{CC} = 5 \text{ V}, \text{ V}_{B} = 2.5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$ |      |     | 0.2  | V    |
| Input resistance                        | R <sub>1</sub>                 |  | -30% | 10  | +30% | kΩ   |
| Resistance ratio                        | R <sub>1</sub> /R <sub>2</sub> |  | 0.8  | 1.0 | 1.2  |      |
| Transition frequency                    | f <sub>T</sub>                 | $V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$                        |      | 150 |      | MHz  |

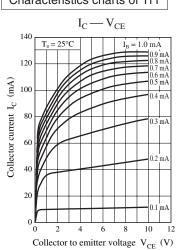
Note) The part number in the parenthesis shows conventional part number.

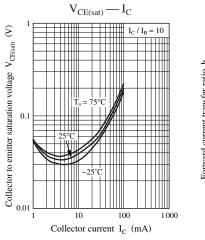
### $\blacksquare$ Electrical Characteristics (continued) $T_a = 25^\circ C \pm 3^\circ C$

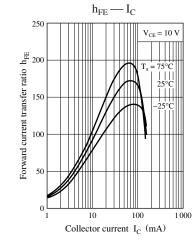
| Parameter                               | Symbol                         | Conditions   | Min  | Тур | Max    | Unit |
|---|--------------------------------|--|------|-----|--------|------|
| Collector to base voltage               | V <sub>CBO</sub>               | $I_{\rm C} = -10 \ \mu A, \ I_{\rm E} = 0$   | -50  |     |        | V    |
| Collector to emitter voltage            | V <sub>CEO</sub>               | $I_{\rm C} = -2  {\rm mA},  I_{\rm B} = 0$   | -50  |     |        | V    |
| Collector cutoff current                | I <sub>CBO</sub>               | $V_{CB} = -50 \text{ V}, I_E = 0$  |      |     | - 0.1  | μΑ   |
|   | I <sub>CEO</sub>               | $V_{CE} = -50 \text{ V}, I_B = 0$  |      |     | - 0.5  |      |
| Emitter cutoff current                  | I <sub>EBO</sub>               | $V_{EB} = -6 V, I_C = 0$   |      |     | - 0.5  | mA   |
| Forward current transfer ratio          | $h_{FE}$                       | $V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$  | 35   |     |        |      |
| Collector to emitter saturation voltage | V <sub>CE(sat)</sub>           | $I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -0.3 \text{ mA}$                                  |      |     | - 0.25 | V    |
| High-level output voltage               | V <sub>OH</sub>                | $V_{CC} = -5 \text{ V},  V_{B} = -0.5  \text{V},  \text{R}_{L} = 1  \text{k}\Omega$        | -4.9 |     |        | V    |
| Low-level output voltage                | V <sub>OL</sub>                | $V_{CC} = -5 \text{ V},  \text{V}_{B} = -2.5  \text{V},  \text{R}_{L} = 1  \text{k}\Omega$ |      |     | - 0.2  | V    |
| Input resistance                        | R <sub>1</sub>                 |  | -30% | 10  | +30%   | kΩ   |
| Resistance ratio                        | R <sub>1</sub> /R <sub>2</sub> |  | 0.8  | 1.0 | 1.2    |      |
| Transition frequency                    | $f_{T}$                        | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$                          |      | 80  |        | MHz  |

#### Common characteristics chart

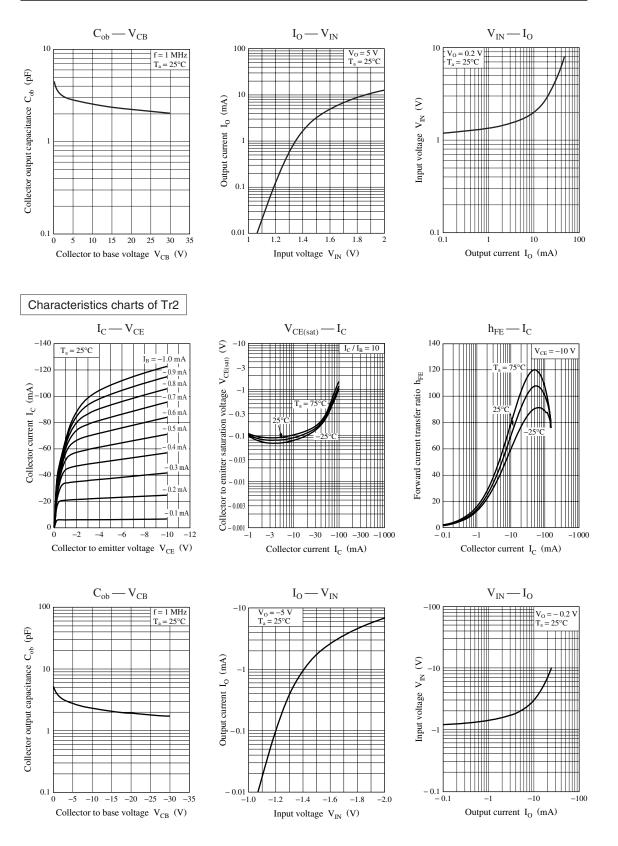








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